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FDBL86563-F085

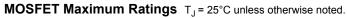
N-Channel PowerTrench[®] MOSFET 60 V, 240 A, 1.5 m Ω

Features

- Typical $R_{DS(on)}$ = 1.1 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical $Q_{g(tot)}$ = 130 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems



Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		60	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
ID	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	240		
	Pulsed Drain Current	T _C = 25°C	See Figure 4	— A	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	614	mJ	
P _D	Power Dissipation		357	W	
	Derate Above 25°C		2.38	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.42	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

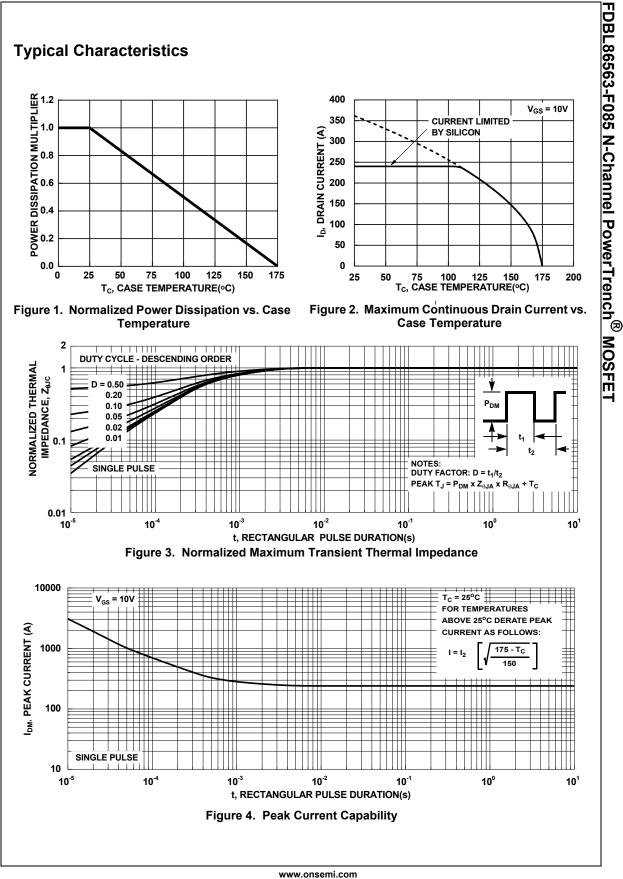
- 1: Current is limited by silicon.
- 2: Starting $T_J = 25^{\circ}C$, L = 0.3mH, $I_{AS} = 64A$, $V_{DD} = 60V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche.
- 3: $R_{\theta,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta,JC}$ is guaranteed by design, while $R_{\theta,JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

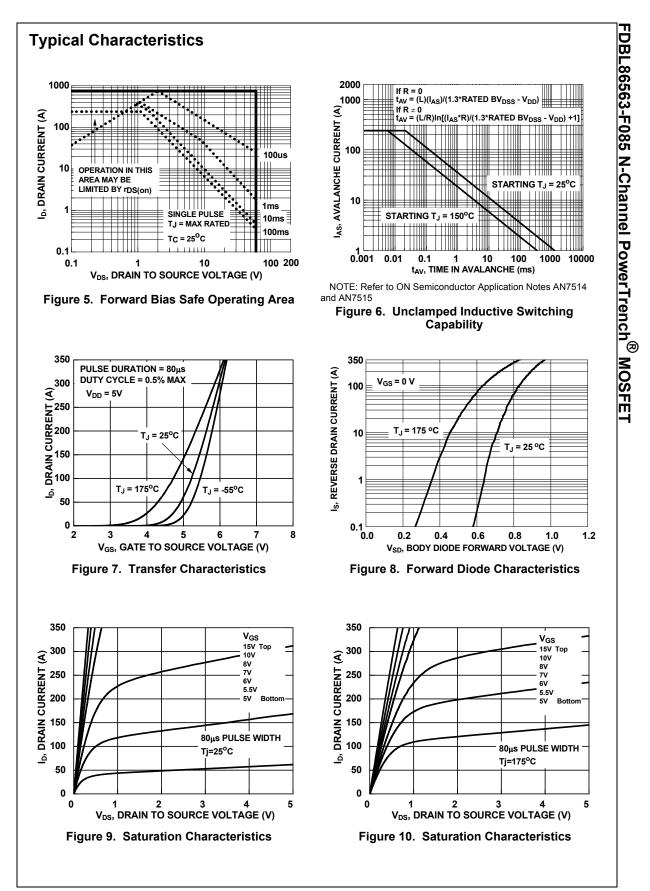
Package Marking and Ordering Information

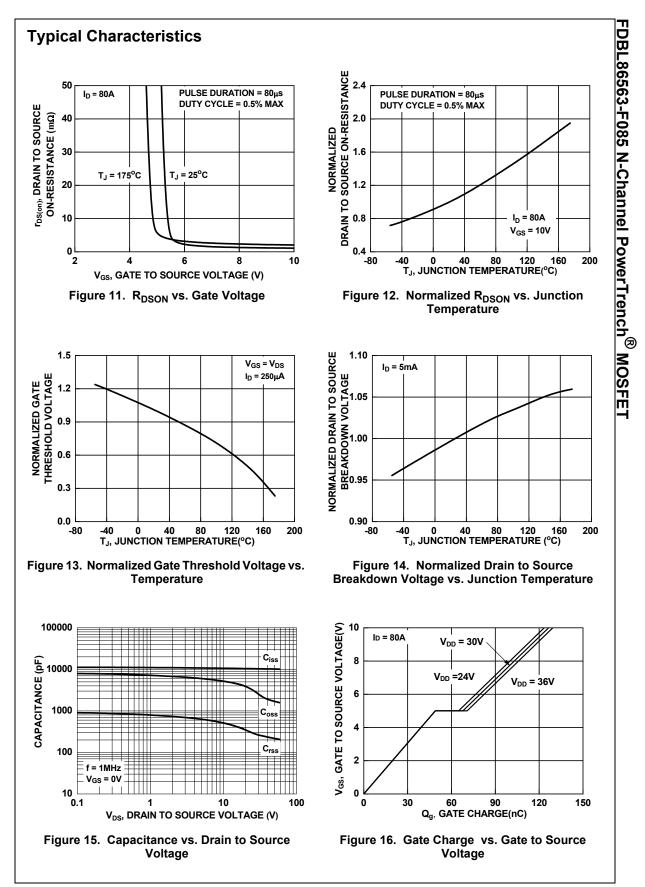
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDBL86563	FDBL86563-F085	MO-299A	13"	24mm	2000 units



Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						1
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V	_{GS} = 0V	60	-	-	V
	-	V _{DS} =60V,		-	-	1	μA
IDSS	Drain-to-Source Leakage Current		T _{.1} = 175 ^o C (Note	4) -	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V _{GS} = ±20V		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D}$, = 250μA	2.0	2.9	4.0	V
	Drain to Source On Resistance	D .	T _J = 25 ^o C	-	1.1	1.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	$T_{\rm J} = 175^{\rm o}C$ (Note	- (94)	2.1	2.9	mΩ
-	c Characteristics				40000		
C _{iss}	Input Capacitance	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz		-	10300	-	pF
C _{oss}	Output Capacitance			-	2590	-	pF
C _{rss}	Reverse Transfer Capacitance Gate Resistance			-	270 4.3	-	pF
R _g		f = 1MHz		-	4.3	- 169	Ω nC
Q _{g(ToT)}	Total Gate Charge at 10V	$V_{GS} = 0 \text{ to } 10^{\circ}$			130	-	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2V	I _D = 80A	-	48	-	nC
Q _{gs}	Gate-to-Source Gate Charge Gate-to-Drain "Miller" Charge			-	20	-	nC
Q _{gd}				-	20	-	no
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	160	ns
t _{d(on)}	Turn-On Delay				30	-	ns
t _r	Rise Time	V_{DD} = 30V, I _D = 80A, V_{GS} = 10V, R _{GEN} = 6 Ω		-	77	-	ns
t _{d(off)}	Turn-Off Delay			-	78	-	ns
t _f	Fall Time			-	57	-	ns
t _{off}	Turn-Off Time			-	-	200	ns
Drain-S	ource Diode Characteristics						
\/	Source to Drain Diade Voltana	I _{SD} =80A, V _{GS} = 0V		-	-	1.25	V
V_{SD}	Source-to-Drain Diode Voltage	I _{SD} = 40A, V ₀		-	-	1.2	V
t _{rr}	Reverse-Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/μs, V _{DD} =48V		-	94	140	ns
Q _{rr}	Reverse-Recovery Charge			-	131	200	nC







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